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View Online at https://aerobasegroup.com/nsn/5962-01-307-5784 **Overall Length:** 0.540 inches **Overall Height:** 0.100 inches **Overall Width:** 1.040 inches **Body Length:** 0.540 inches **Body Width:** 0.300 inches **Body Height:** 0.100 inches **Maximum Power Dissipation Rating:** 1.2 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Bipolar and burn in and monolithic and programmable and w/resistor **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Bipolar metal-oxide semiconductor **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** F-9 mil-m-38510 **Terminal Surface Treatment:** Voltage Rating And Type Per Characteristic: 5.0 volts power source **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 flat leads Shelf Life:

N/a

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In	18	<i>(</i>)+	МЛО	201	ure:

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Demilitarization:

No

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